

RELIABILITY REPORT
FOR
MAX6361xUTxx
PLASTIC ENCAPSULATED DEVICES

August 4, 2006

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR.
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Written by

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Conclusion

The MAX6361 successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

Table of Contents

I.Device Description	V.Quality Assurance Information
II.Manufacturing Information	VI.Reliability Evaluation
III.Packaging Information	IV.Die Information
.....Attachments	

I. Device Description

A. General

The MAX6361 supervisory circuit reduces the complexity and number of components required for power-supply monitoring and battery control functions in microprocessor (μ P) systems. The circuit significantly improves system reliability and accuracy compared to that obtainable with separate ICs or discrete components. Its functions include μ P reset, backup battery switchover, and power failure warning.

The MAX6361 operates from supply voltages as low as +1.2V. The factory-preset reset threshold voltage ranges from 2.32V to 4.63V (see *Ordering Information*). This device provides a manual reset input. In addition, each part type is offered in three reset output versions: an active-low push-pull reset, an active-low open-drain reset, and an active-high open-drain reset (see *Selector Guide* at end of data sheet).

B. Absolute Maximum Ratings

<u>Item</u>	<u>Rating</u>
Terminal Voltages (with respect to GND)	
VCC, BATT, OUT	-0.3V to +6V
RESET (open drain), RESET (open drain)	-0.3V to +6V
BATT ON, RESET (push-pull), RESET IN,	
WDI	-0.3V to (VOUT + 0.3V)
MR	-0.3V to (VCC + 0.3V)
Input Current	
VCC Peak	1A
VCC Continuous	250mA
BATT Peak	250mA
BATT Continuous	40mA
GND	75mA
Output Current	
OUT	Short-Circuit Protection for up to 10s
RESET, RESET, BATT ON	20mA
Continuous Power Dissipation (TA = +70°C)	
6-Pin SOT23 (derate 8.70mW/°C above +70°C)	696mW
Operating Temperature Range	-40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

II. Manufacturing Information

A. Description/Function:	SOT23, Low-Power μ P Supervisory Circuits with Battery Backup
B. Process:	B8 (Standard 0.8 micron silicon gate CMOS)
C. Number of Device Transistors:	720
D. Fabrication Location:	California, USA
E. Assembly Location:	Malaysia, Philippines, or Thailand
F. Date of Initial Production:	January, 2000

III. Packaging Information

A. Package Type:	6-Pin SOT23-6
B. Lead Frame:	Copper
C. Lead Finish:	Solder Plate or 100% Matte Tin
D. Die Attach:	Silver-Filled Epoxy
E. Bondwire:	Gold (1 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	# 05-1601-0090
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C:	Level 1

IV. Die Information

A. Dimensions:	57 x 35 mils
B. Passivation:	$\text{Si}_3\text{N}_4/\text{SiO}_2$ (Silicon nitride/ Silicon dioxide)
C. Interconnect:	Aluminum/Si (Si = 1%)
D. Backside Metallization:	None
E. Minimum Metal Width:	0.8 microns (as drawn)
F. Minimum Metal Spacing:	0.8 microns (as drawn)
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO_2
I. Die Separation Method:	Wafer Saw

V. Quality Assurance Information

- A. Quality Assurance Contacts: Jim Pedicord (Manager, Reliability Operations)
Bryan Preeshl (Managing Director of QA)
- B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.
0.1% For all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4340 \times 160 \times 2} \quad (\text{Chi square value for MTTF upper limit})$$

△ Temperature Acceleration factor assuming an activation energy of 0.8eV

$$\lambda = 6.87 \times 10^{-9}$$

$$\lambda = 6.87 \text{ F.I.T. (60\% confidence level @ 25°C)}$$

This low failure rate represents data collected from Maxim's reliability monitor program. In addition to routine production Burn-In, Maxim pulls a sample from every fabrication process three times per week and subjects it to an extended Burn-In prior to shipment to ensure its reliability. The reliability control level for each lot to be shipped as standard product is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Attached Burn-In Schematic (Spec. # 06-5517) shows the static Burn-In circuit. Maxim performs failure analysis on any lot that exceeds this reliability control level. Maxim also performs quarterly 1000 hour life test monitors. This data is published in the Product Reliability Report (**RR-1N**). Current monitor data for the B8/S8 Process results in a FIT rate of 0.17 @ 25°C and 2.92 @ 55°C (eV = 0.8, UCL = 60%).

B. Moisture Resistance Tests

Maxim pulls pressure pot samples from every assembly process three times per week. Each lot sample must meet an LTPD = 20 or less before shipment as standard product. Additionally, the industry standard 85°C/85%RH testing is done per generic device/package family once a quarter.

C. E.S.D. and Latch-Up Testing

The MS35 die type has been found to have all pins able to withstand a transient pulse of $\pm 600\text{V}$, per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of $\pm 250\text{mA}$.

Table 1
Reliability Evaluation Test Results

MAX6361xUTxx

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	PACKAGE	SAMPLE SIZE	NUMBER OF FAILURES
Static Life Test (Note 1)					
	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality		160	0
Moisture Testing (Note 2)					
Pressure Pot	Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs.	DC Parameters & functionality	SOT	77	0
85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality		77	0
Mechanical Stress (Note 2)					
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters & functionality		77	0

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data

Attachment #1

TABLE II. Pin combination to be tested. 1/ 2/

	Terminal A (Each pin individually connected to terminal A with the other floating)	Terminal B (The common combination of all like-named pins connected to terminal B)
1.	All pins except V_{PS1} <u>3/</u>	All V_{PS1} pins
2.	All input and output pins	All other input-output pins

1/ Table II is restated in narrative form in 3.4 below.

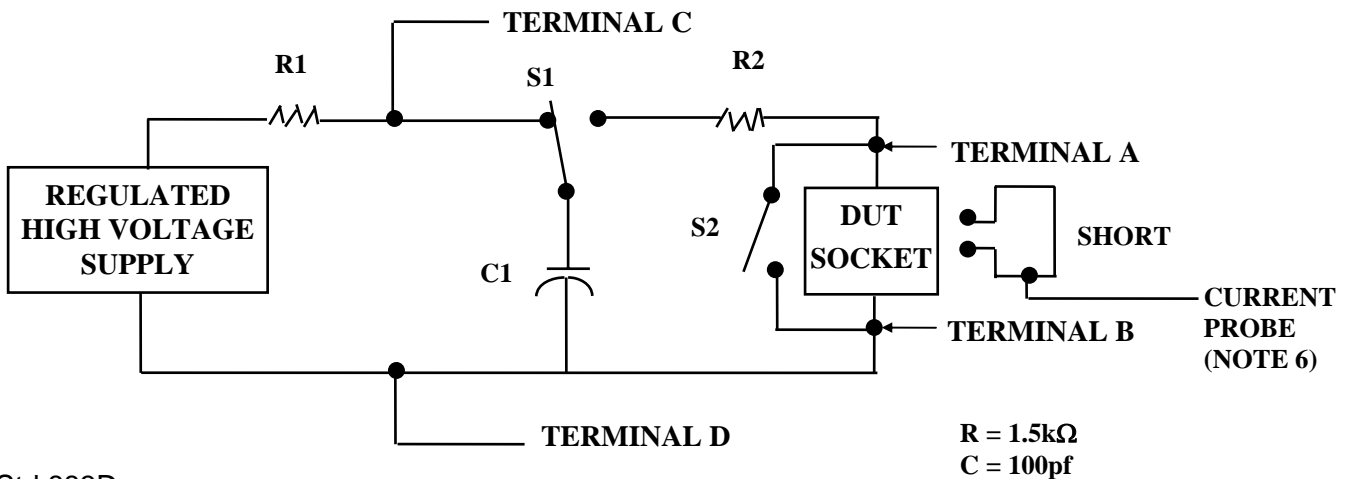
2/ No connects are not to be tested.

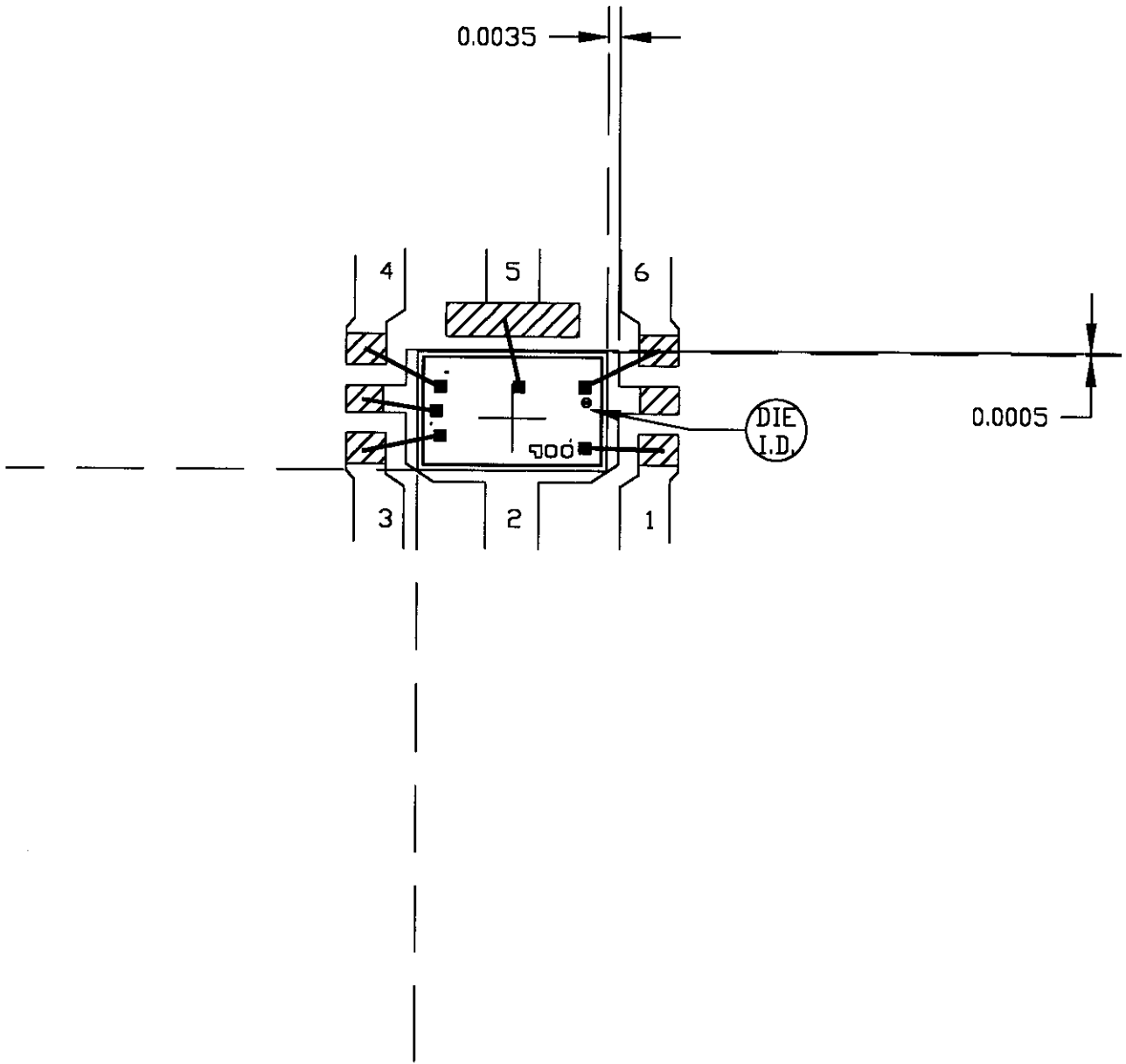
3/ Repeat pin combination I for each named Power supply and for ground

(e.g., where V_{PS1} is V_{DD} , V_{CC} , V_{SS} , V_{BB} , GND, $+V_S$, $-V_S$, V_{REF} , etc).

3.4 Pin combinations to be tested.

- a. Each pin individually connected to terminal A with respect to the device ground pin(s) connected to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
- b. Each pin individually connected to terminal A with respect to each different set of a combination of all named power supply pins (e.g., V_{SS1} , or V_{SS2} or V_{SS3} or V_{CC1} , or V_{CC2}) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.
- c. Each input and each output individually connected to terminal A with respect to a combination of all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.





NOTE: CAVITY DOWN

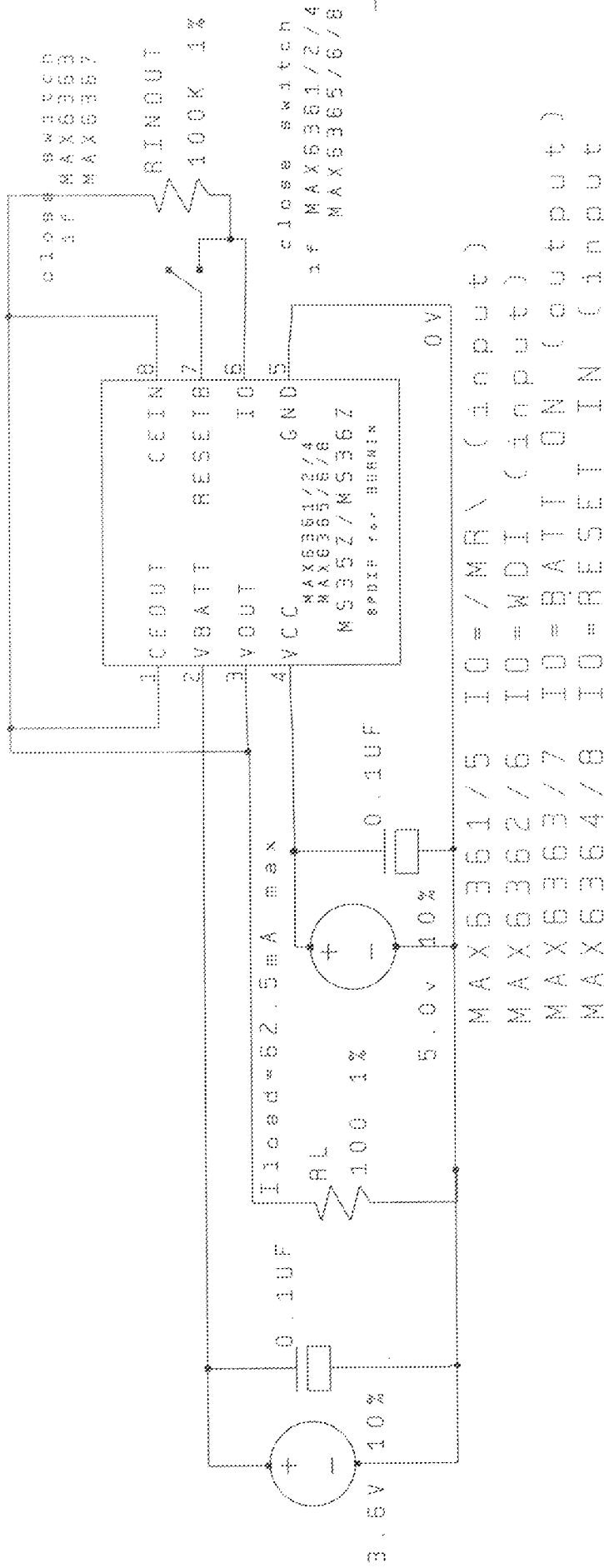
PKG.CODE:	U6-1	
CAV./PAD SIZE:	64x39	PKG. DESIGN

APPROVALS

DATE

MAXIM	
BUILDSHEET NUMBER:	REV.:
05-1601-0090	A

MS35Z / MS36Z BURN-IN SCHEMATIC for MAX6361/2/4 & MAX6365/6/8



Total Chip Power Dissipation Max 25mW
 Total External Resistor Power Dissipation Max 300mW
 8 PDIP for Burn In

MAXIM CONFIDENTIAL	CREATED: 00/00/00	BY: ET	ENG2: -
MS35Z/MS36Z BURN IN I	LAST SAVED: 8-24-1999.11.45	PROJECT: MS35Z/MS36Z	DWG NO. - 026 5517
		DESC: MAX6361/2/4, 6/6/8	MAX6361/2/4/6/8
		FILE: MS35B11	SHEET 3 OF 1